## NSN 5961-01-204-6179

Transistor - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5961-01-204-6179 **Inclosure Material:** Metal **Overall Length:** 1.563 inches **Overall Height:** 0.350 inches **Overall Width:** 1.050 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-3 **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 80.0 collector to base voltage/static/emitter open and 60.0 collector to emitter voltage/static/base open and 6.0 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** 10.00 amperes source cutoff current and 3.00 amperes source cutoff current **Power Rating Per Characteristic:** 100.0 watts small-signal input power, common-collector absolute **Transfer Ratio:** 200.0 static forward current transfer ratio, common-emitter **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: pnp **Precious Material And Location:** Leads gold

Gold

**Terminal Type And Quantity:** 

2 pin and 1 case

**Precious Material:** 

Shelf Life:

N/a

## NSN 5961-01-204-6179

Transistor - Page 2 of 2



ш	ın	10	<i>(</i> )+	Measure:	

--

Demilitarization:

No

Fiig:

A110a0